NSN 5962-01-382-8175

Memory Microcircuit - Page 1 of 1



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Features Provided:

Programmed and electrostatic sensitive and erasable

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Case Outline Source And Designator:

D-9 mil-m-38510

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Pal

Hybrid Technology Type:

Monolithic

Terminal Type And Quantity:

24 printed circuit

Departure From Cited Designator:

Programmed per: tt8512149-101

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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